











SN74AUP1T34-Q1

SCES852A - DECEMBER 2013-REVISED APRIL 2016

## SN74AUP1T34-Q1 1-Bit Unidirectional Voltage-Level Translator

### **Features**

- **Qualified for Automotive Applications** 
  - AEC-Q100 Qualified
  - Device Temperature Grade 1: -40°C to 125°C Ambient Operating Temperature
  - Device HBM ESD Classification Level 3A
  - Device CDM ESD Classification Level C5
- Wide Operating VCC Range of 0.9 V to 3.6 V
- Balanced Propagation Delays: t<sub>PLH</sub> = t<sub>PHL</sub> (1.8-V to 3.3-V Translation Typical)
- Low Static-Power Consumption: Maximum of 5-µA
- ±6-mA Output Drive at 3 V
- I<sub>off</sub> Supports Partial Power-Down-Mode Operation
- VCC Isolation Feature If V<sub>CCA</sub> Input Is at GND, B Port Is in the High-Impedance state
- Input Hysteresis Allows Slow Input Transition and Better Switching Noise Immunity at Input
- ESD Protection Exceeds JESD 22
- 5000-V Human-Body Model (AEC-Q100-002-E)
- Latch-Up Performance Meets 100 mA Per Q100-004-D

## 2 Applications

- Automotive
- Enterprise
- Industrial
- Personal Electronics
- **Telecommunications**

## Description

The SN74AUP1T34-Q1 device is a 1-bit noninverting translator that uses two separate configurable powersupply rails. It is a unidirectional translator from A to B. The A port is designed to track V<sub>CCA</sub>. V<sub>CCA</sub> accepts supply voltages from 0.9 V to 3.6 V. The B port is designed to track  $V_{\rm CCB}$ .  $V_{\rm CCB}$  accepts supply voltages from 0.9 V to 3.6 V. This allows for low-voltage translation between 1-V, 1.2-V, 1.5-V, 1.8-V, 2.5-V, and 3.3-V voltage nodes. The SN74AUP1T34-Q1 is specified partial-power-down fully for also applications using  $I_{\text{off}}$ . The  $I_{\text{off}}$  circuitry disables the outputs, preventing damaging current backflow through the device when it is powered down.

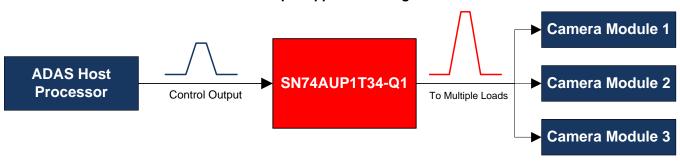
The VCC isolation feature ensures that if V<sub>CCA</sub> input is at GND, the B port is in the high-impedance state. If V<sub>CCB</sub> input is at GND, any input to the A side does not cause the leakage current even floating.

## Device Information<sup>(1)</sup>

PART NUMBER	PACKAGE	BODY SIZE (NOM)		
SN74AUP1T34-Q1	SC70 (5)	2.00 mm × 1.25 mm		

(1) For all available packages, see the orderable addendum at the end of the data sheet.

### **Example Application Diagram**



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## 4 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

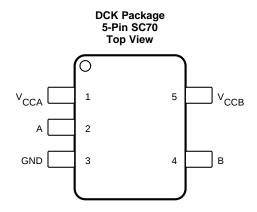
## Changes from Original (December 2013) to Revision A

**Page** 

- Added ESD Ratings table, Feature Description section, Device Functional Modes, Application and Implementation section, Power Supply Recommendations section, Layout section, Device and Documentation Support section, and



## 5 Pin Configuration and Functions



## **Pin Functions**

	PIN	1/0	DECODIDETION				
NAME	NO.	I/O	DESCRIPTION				
Α	2	1	I Input Port. Referenced to V <sub>CCA</sub> .				
В	4	0	Output Port. Referenced to V <sub>CCB</sub> .				
GND	3	_	Ground.				
V <sub>CCA</sub>	1	<ul> <li>Input Port DC Power Supply.</li> </ul>					
V <sub>CCB</sub>	5	Output Port DC Power Supply.					

## 6 Specifications

## 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)

			MIN	MAX	UNIT
$V_{\rm CCA}, \ V_{\rm CCB}$	Supply voltage		-0.3	4	V
$V_{I}$	Input voltage	-0.5	4.6	V	
V	Voltage applied to any outp	-0.5	4.6	V	
Vo	Voltage applied to any outp	-0.5	4.6	\ \	
I <sub>IK</sub>	Input clamp current	V <sub>1</sub> < 0		-50	mA
I <sub>OK</sub>	Output clamp current	V <sub>O</sub> < 0		-50	mA
Io	Continuous output current			±50	mA
	Continuous current through	VCCA or GND		±100	mA
T <sub>stg</sub>	Storage temperature	-65	150	°C	

## 6.2 ESD Ratings

			VALUE	UNIT
Floatmontatio	Human-body model (HBM), per ANSI/ESDA/JEDEC JS-001 (1), Classification 3A			
V <sub>(ESD)</sub>	Electrostatic discharge	Charged-device model (CDM), per JEDEC specification JESD22-C101 (2), Classification C5	750	V

<sup>(1)</sup> JEDEC document JEP155 states that 500-V HBM allows safe manufacturing with a standard ESD control process.

Product Folder Links: SN74AUP1T34-Q1

<sup>(2)</sup> JEDEC document JEP157 states that 250-V CDM allows safe manufacturing with a standard ESD control process.



## 6.3 Recommended Operating Conditions

over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST COND	ITIONS	VCCA	VCCB	MIN	MAX	UNIT
V <sub>CCA</sub> , V <sub>CCB</sub>	Supply voltage					0.9	3.6	٧
				0.9 V to 1.95 V	0.9 V to 1.95 V	0.65 × V <sub>CCA</sub>		
$V_{IH}$	High-level input voltage			2.3 V to 2.7 V	0.9 V to 3.6 V	1.6		V
				3 V to 3.6 V	0.9 V to 3.6 V	2		
				0.9 V	0.9 V to 1.95 V		0.3 × V <sub>CCA</sub>	
.,				1 V to 1.95 V	0.9 V to 1.95 V		0.35 × V <sub>CCA</sub>	.,
$V_{IL}$	Low-level input voltage			2.3 V to 2.7 V	0.9 V to 3.6 V		0.7	V
				3 V to 3.6 V	0.9 V to 3.6 V		0.9	
Δt/Δν	Input transition rise or fall rate			3 V to 3.6 V	0.9 V to 3.6 V		200	ns/V
T <sub>A</sub>	Operating free-air temperature					-40	125	°C
		I <sub>OH</sub> = -100 μA		0.9 V to 3.6 V	0.9 V to 3.6 V	VCCB - 0.2		
		$I_{OH} = -0.25 \text{ mA}$		0.9 V to 1 V	0.9 V to 1 V	0.75 × VCCB		
		I <sub>OH</sub> = -1.5 mA	., .,	1.2 V	1.2 V	1		V
$V_{OH}$		I <sub>OH</sub> = -2 mA	$V_I = V_{IH}$	1.65 V	1.65 V	1.32		
		$I_{OH} = -3 \text{ mA}$		2.3 V	2.3 V	1.9		
		$I_{OH} = -6 \text{ mA}$		3 V	3 V	2.72		
		I <sub>OL</sub> = 100 μA		0.9 V to 3.6 V	0.9 V to 3.6 V		0.1	
		I <sub>OL</sub> = 0.25 mA		0.9 V to 1 V	0.9 V 1 V		0.1	
		I <sub>OL</sub> = 1.5 mA	, , ,,	1.2 V 1.2 V		0.3 × VCCB	V	
$V_{OL}$		I <sub>OL</sub> = 2 mA	$V_I = V_{IL}$	1.65 V	1.65 V		0.31	
		I <sub>OL</sub> = 3 mA		2.3 V	2.3 V		0.31	
		I <sub>OL</sub> = 6 mA		3 V	3 V		0.31	
I <sub>I</sub>	Control inputs	V <sub>I</sub> = VCCA or GND		0.9 V to 3.6 V	0.9 V to 3.6 V		±1	μΑ
	A D t	\/I ==\/O		0 V	0 V to 3.6 V		±5	
l <sub>off</sub>	A or B port	VI or VO = 0 to 3.6 V		0 V to 3.6 V	0 V		±5	μA
				0.9 V to 3.6 V	0.9 V to 3.6 V		2.7	
		VI VCCI or CND IO	0 1	0.9 V to 3.6 V	VCCA		2	
I <sub>CCA</sub>		VI = VCCI or GND, IO	= U MA	0 V	0 V to 3.6 V		1	μA
				0 V to 3.6 V	0 V		1	
				0.9 V to 3.6 V	0.9 V to 3.6 V		2.7	
		VI VOOL 0115 13	0 4	0.9 V to 3.6 V	VCCA		2	*
I <sub>CCB</sub>		VI = VCCI or GND, IO = 0 mA		0 V	0 V to 3.6 V		1	μA
				0 V to 3.6 V	0 V		1	
I <sub>CCA</sub> + I <sub>C</sub>	СВ	VI = VCCI or GND, IO	= 0 mA	0.9 V to 3.6 V	0.9 V to 3.6 V		5.4	μΑ
C <sub>io</sub>	A or B port			3.3 V	3.3 V		4	pF

## 6.4 Thermal Information

		SN74AUP1T34-Q1		
	THERMAL METRIC <sup>(1)</sup>	DCK (SC70)	UNIT	
		5 PINS		
$R_{\theta JA}$	Junction-to-ambient thermal resistance	301.9	°C/W	
R <sub>θJC(top)</sub>	Junction-to-case (top) thermal resistance	113	°C/W	
$R_{\theta JB}$	Junction-to-board thermal resistance	79.1	°C/W	
Ψлτ	Junction-to-top characterization parameter	3.9	°C/W	
ΨЈВ	Junction-to-board characterization parameter	78.3	°C/W	

<sup>(1)</sup> For more information about traditional and new thermal metrics, see the Semiconductor and IC Package Thermal Metrics application report, SPRA953.

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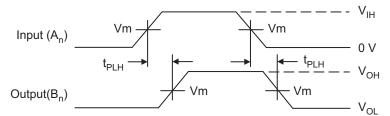
Product Folder Links: SN74AUP1T34-Q1



## 6.5 AC Electrical Characteristics

over operating free-air temperature range (unless otherwise noted)

DADAMETED		V004	VCCB = 0	).9 V	VCCB = 1.2	2 V	VCCB = 1.	65 V	VCCB =	2.3 V	VCCB =	= 3 V	LINUT
PARAMETER	CL	VCCA	TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX	TYP	MAX	UNIT
	5 pF	0.9 V	25		18		16.2		16.3		16.8		
	5 pF	1.2 V		42.5		24.9		23.2		22.6		22.5	
t <sub>PLH</sub> /t <sub>PHL</sub>	5 pF	1.65 V		40		10.7		8.84		8.08		7.88	ns
	5 pF	2.3 V		41.3		8.02		5.73		4.92		4.2	
	5 pF	3 V		42.5		7.61		4.5		3.65		3.39	
	10 pF	0.9 V	28.9		19.8		17.9		18		18.5		
	10 pF	1.2 V		43.22		12.33		9.57		8.81		8.61	
t <sub>PLH</sub> /t <sub>PHL</sub>	10 pF	1.65 V		40.44		9.21		6.57		5.6		4.73	ns
	10 pF	2.3 V		41.56		8.3		5.54		4.42		4.07	
	10 pF	3 V		42.81		7.87		4.8		3.8		3.36	
	15 pF	0.9 V	30.6		21.6		19.6		19.7		20.3		
	15 pF	1.2 V		43.87		16.2		11.8		11		11	
t <sub>PLH</sub> /t <sub>PHL</sub>	15 pF	1.65 V		40.78		14.7		8.8		7.1		6.4	ns
	15 pF	2.3 V		41.79		14.9		7.6		5.88		5.27	
	15 pF	3 V		43.09		16.2		6.98		5.4		4.7	
	30 pF	0.9 V	32.1		21.3		18.7		18		18.3		
	30 pF	1.2 V		45.65		15.1		12.37		11.61		11.41	
t <sub>PLH</sub> /t <sub>PHL</sub>	30 pF	1.65 V		41.72		12.18		8.15		6.94		6.1	ns
	30 pF	2.3 V		42.44		12.35		7.25		5.55		4.97	
	30 pF	3 V		43.69		11.6		6.92		4.95		4.35	



 $V_{MI} = V_{IH}/2$ ;  $V_{MO} = V_{CCB}/2$ 

 $t_{R}$  =  $t_{F}$  = 2.0 ns, 10% to 90%; f = 1 MHz;  $t_{W}$  = 500 ns

Figure 1. Waveform 1 - Propagation Delays

# TEXAS INSTRUMENTS

## 6.6 Typical Characteristics

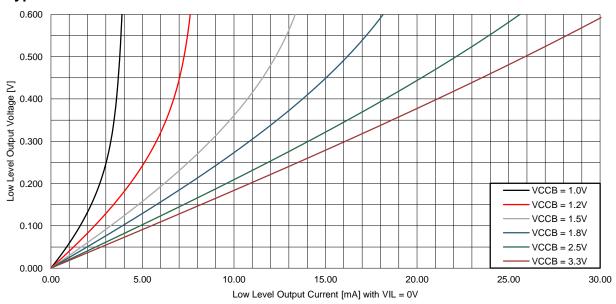
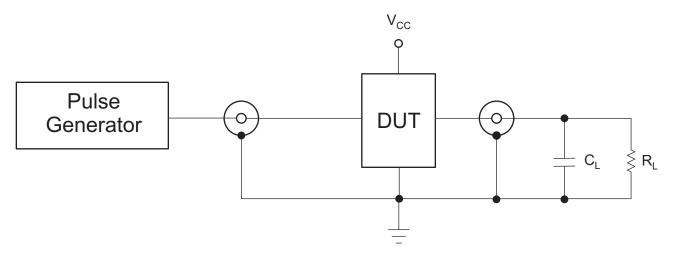


Figure 2. Low Level Output Voltage vs Low Level Output Current

## 7 Parameter Measurement Information



## **TEST**

 $t_{PLH}, t_{PHL}$ 

C<sub>L</sub> = 5 pF, 10 pF, 15 pF, 30 pF or equivalent (includes probe and jig capacitance)

 $R_L = 1 M\Omega$  or equivalent

 $Z_{OUT}$  of pulse generator = 50  $\Omega$ 

Figure 3. AC (Propagation Delay) Test Circuit

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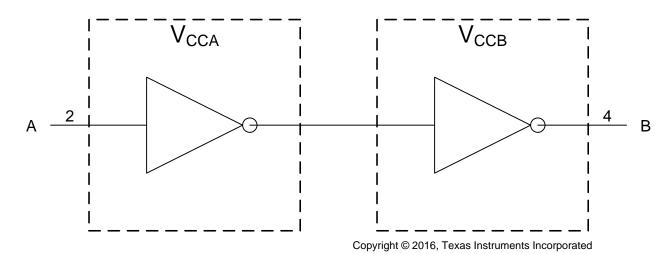


## **Detailed Description**

#### Overview 8.1

The SN74AUP1T34-Q1 is a unidirectional, single-bit, dual-supply, noninverting voltage-level translator. Pin A, which is referenced to V<sub>CCA</sub>, receives the signal that is to be level translated. Pin B, which is referenced to V<sub>CCB</sub>, transmits the level translated signal. Both supply pins V<sub>CCA</sub> and V<sub>CCB</sub> support a voltage range from 0.9 V to 3.6 V.

## 8.2 Functional Block Diagram



### 8.3 Feature Description

### 8.3.1 Fully Configurable Dual-Rail Design

Both V<sub>CCA</sub> and V<sub>CCB</sub> can be supplied at any voltage from 0.9 V to 3.6 V, making the device suitable for translating between any of the voltage nodes (1 V, 1.2 V, 1.8 V, 2.5 V, and 3.3 V).

#### 8.3.2 Partial-Power-Down Mode Operation

I<sub>off</sub> circuitry disables the outputs, preventing damaging current backflow through the SN74AUP1T34-Q1 when it is powered down. This can occur in applications where subsections of a system are powered down (partial-powerdown) to reduce power consumption.

## 8.3.3 V<sub>CC</sub> Isolation

The  $V_{CC}$  isolation feature ensures that if either  $V_{CCA}$  or  $V_{CCB}$  are at GND (or < 0.4 V), both ports A and B are set to a high-impedance state, preventing false logic levels from being presented to either bus.

#### 8.3.4 Input Hysteresis

Input hysteresis allows the input to support slew rates as slow as 200 ns/V, improving switching noise immunity.

## 8.4 Device Functional Modes

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Table 1 lists the functional modes of the SN74AUP1T34-Q1.

**Table 1. Function Table** 

INPUT	OUTPUT
A PORT	B PORT
L	L
Н	Н



## 9 Application and Implementation

#### NOTE

Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes. Customers should validate and test their design implementation to confirm system functionality.

## 9.1 Application Information

The SN74AUP1T34-Q1 can be used in level-translation applications for interfacing devices or systems operating at different interface voltages with one another.

## 9.2 Typical Application

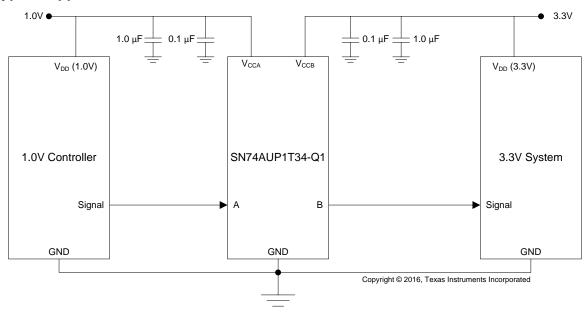


Figure 4. Typical Application Example

## 9.2.1 Design Requirements

Table 2 lists the design requirements of the SN74AUP1T34-Q1.

**Table 2. Design Parameters** 

DESIGN PARAMETER	EXAMPLE VALUE
Input Voltage Range	0.9 V to 3.6 V
Output Voltage Range	0.9 V to 3.6 V

### 9.2.2 Detailed Design Procedure

To begin the design process, determine the following:

- Input voltage range
  - Use the supply voltage of the device that is driving the SN74AUP1T34-Q1 device to determine the input voltage range. For a valid logic-high, the value must exceed the V<sub>IH</sub> of the input port. For a valid logic low the value must be less than the V<sub>IL</sub> of the input port.
- Output voltage range
  - Use the supply voltage of the device that the SN74AUP1T34-Q1 device is driving to determine the output voltage range.

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## 9.2.3 Application Curve

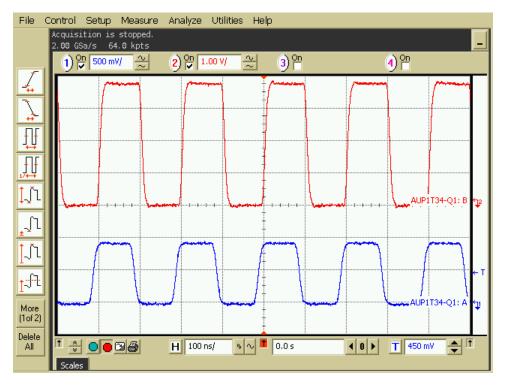


Figure 5. 10 MHz Up Translation (0.9 V to 3.6 V)

## 10 Power Supply Recommendations

Connect ground before applying either  $V_{CCA}$  or  $V_{CCB}$ . There is no specific power sequence requirement for the SN74AUP1T34.  $V_{CCA}$  or  $V_{CCB}$  may be powered up first, and  $V_{CCA}$  or  $V_{CCB}$  may be powered down first.

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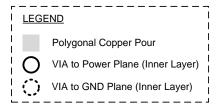
## 11 Layout

## 11.1 Layout Guidelines

To ensure reliability of the device, TI recommends following common printed-circuit board layout guidelines.

- · Bypass capacitors must be used on power supplies.
- Short trace lengths must be used to avoid excessive loading.
- Placing pads on the signal paths for loading capacitors or pullup resistors helps adjust rise and fall times of signals depending on the system requirements.

## 11.2 Layout Example



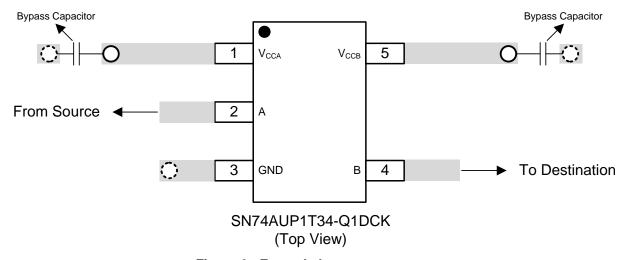


Figure 6. Example Layout

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## 12 Device and Documentation Support

## 12.1 Community Resources

The following links connect to TI community resources. Linked contents are provided "AS IS" by the respective contributors. They do not constitute TI specifications and do not necessarily reflect TI's views; see TI's Terms of

TI E2E™ Online Community TI's Engineer-to-Engineer (E2E) Community. Created to foster collaboration among engineers. At e2e.ti.com, you can ask questions, share knowledge, explore ideas and help solve problems with fellow engineers.

Design Support TI's Design Support Quickly find helpful E2E forums along with design support tools and contact information for technical support.

### 12.2 Trademarks

E2E is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

## 12.3 Electrostatic Discharge Caution



These devices have limited built-in ESD protection. The leads should be shorted together or the device placed in conductive foam during storage or handling to prevent electrostatic damage to the MOS gates.

## 12.4 Glossary

SLYZ022 — TI Glossarv.

This glossary lists and explains terms, acronyms, and definitions.

## Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most current data available for the designated devices. This data is subject to change without notice and revision of this document. For browser-based versions of this data sheet, refer to the left-hand navigation.

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www.ti.com 23-May-2025

#### PACKAGING INFORMATION

Orderable part number	Status (1)	Material type	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material	MSL rating/ Peak reflow	Op temp (°C)	Part marking (6)
SN74AUP1T34QDCKRQ1	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	NIPDAU   SN	Level-1-260C-UNLIM	-40 to 125	(U4E, U4J)
SN74AUP1T34QDCKRQ1.B	Active	Production	SC70 (DCK)   5	3000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	(U4E, U4J)

<sup>(1)</sup> Status: For more details on status, see our product life cycle.

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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#### OTHER QUALIFIED VERSIONS OF SN74AUP1T34-Q1:

Catalog: SN74AUP1T34

<sup>(2)</sup> Material type: When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> RoHS values: Yes, No, RoHS Exempt. See the TI RoHS Statement for additional information and value definition.

<sup>(4)</sup> Lead finish/Ball material: Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> MSL rating/Peak reflow: The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> Part marking: There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.



## **PACKAGE OPTION ADDENDUM**

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NOTE: Qualified Version Definitions:

 $_{\bullet}$  Catalog - TI's standard catalog product

## **PACKAGE MATERIALS INFORMATION**

www.ti.com 13-Aug-2023

## TAPE AND REEL INFORMATION





A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

## QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



#### \*All dimensions are nominal

Device	U	Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
SN74AUP1T34QDCKRQ1	SC70	DCK	5	3000	178.0	9.0	2.4	2.5	1.2	4.0	8.0	Q3

## **PACKAGE MATERIALS INFORMATION**

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## \*All dimensions are nominal

Device	Package Type	ackage Type Package Drawing		SPQ	Length (mm)	Width (mm)	Height (mm)	
SN74AUP1T34QDCKRQ1	SC70	DCK	5	3000	190.0	190.0	30.0	



SMALL OUTLINE TRANSISTOR



### NOTES:

- 1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
  2. This drawing is subject to change without notice.
  3. Reference JEDEC MO-203.

- 4. Support pin may differ or may not be present.5. Lead width does not comply with JEDEC.
- 6. Body dimensions do not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.25mm per side



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

7. Publication IPC-7351 may have alternate designs.8. Solder mask tolerances between and around signal pads can vary based on board fabrication site.



SMALL OUTLINE TRANSISTOR



NOTES: (continued)

- 9. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
- 10. Board assembly site may have different recommendations for stencil design.



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